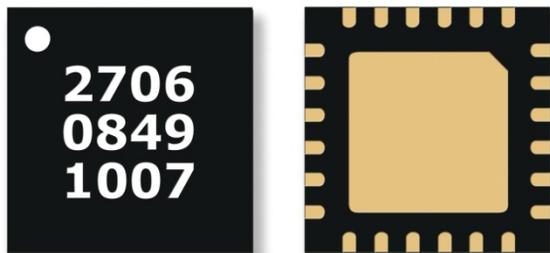
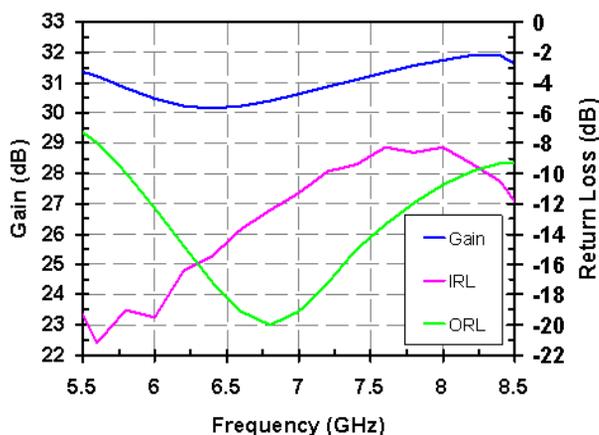
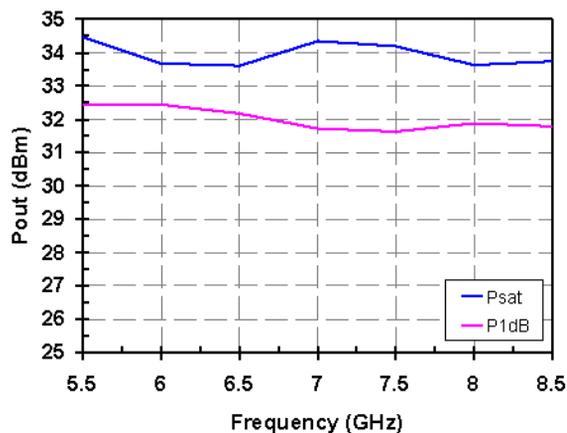


## 2 Watt C-Band Packaged Power Amplifier



### Measured Performance

Bias conditions:  $V_d = 6\text{ V}$ ,  $I_d = 1.26\text{ A}$ ,  $V_g = +0.6\text{ V}$  Typical



### Key Features

- Frequency Range: 5.5 – 8.5 GHz
- Power: 34 dBm Psat, 32 dBm P1dB
- Gain: 31 dB
- TOI: 42 dBm
- NF: 7 dB
- Bias:  $V_d = 6\text{ V}$ ,  $I_d = 1.26\text{ A}$ ,  $V_g = +0.6\text{ V}$  Typical
- Package Dimensions: 5 x 5 x 0.85 mm

### Primary Applications

- Point-to-Point Radio
- Communications

### Product Description

The TriQuint TGA2706-SM is a packaged 2 Watt Power Amplifier for C-band applications. The part is designed using TriQuint's proven standard 0.5um E/D pHEMT production process. The TGA2706-SM provides a nominal 34 dBm of output power at an input power level of 12 dBm with a small signal gain of 31 dB. Nominal TOI is 42 dBm and noise figure is 7 dB.

The TGA2706-SM is a QFN 5x5 mm surface mount package. It is ideally suited for low cost emerging markets such as point to point radio and communications.

Lead-Free & RoHS compliant.

Evaluation boards are available upon request.

*Datasheet subject to change without notice.*

**Table I**  
**Absolute Maximum Ratings 1/**

<b>Symbol</b>	<b>Parameter</b>	<b>Value</b>	<b>Notes</b>
Vd-Vg	Drain to Gate Voltage	16 V	
Vd	Drain Voltage	13 V	2/
Vg	Gate Voltage Range	-0.65 to +2 V	
Id	Drain Current	2.7 A	2/
Ig	Gate Current Range	-16 to 120mA	
Pin	Input Continuous Wave Power	26 dBm	2/

- 1/ These ratings represent the maximum operable values for this device. Stresses beyond those listed under “Absolute Maximum Ratings” may cause permanent damage to the device and / or affect device lifetime. These are stress ratings only, and functional operation of the device at these conditions is not implied.
- 2/ Combinations of supply voltage, supply current, input power, and output power shall not exceed Pd (as listed in “Thermal Information”).

**Table II**  
**Recommended Operating Conditions**

<b>Symbol</b>	<b>Parameter 1/</b>	<b>Value</b>
Vd	Drain Voltage	6 V
Idq	Drain Current	1.26 A
Id_Drive	Drain Current under RF Drive	1.7 A
Vg	Gate Voltage	+0.6 V

- 1/ See assembly diagram for bias instructions.

**Table III**  
**RF Characterization Table**

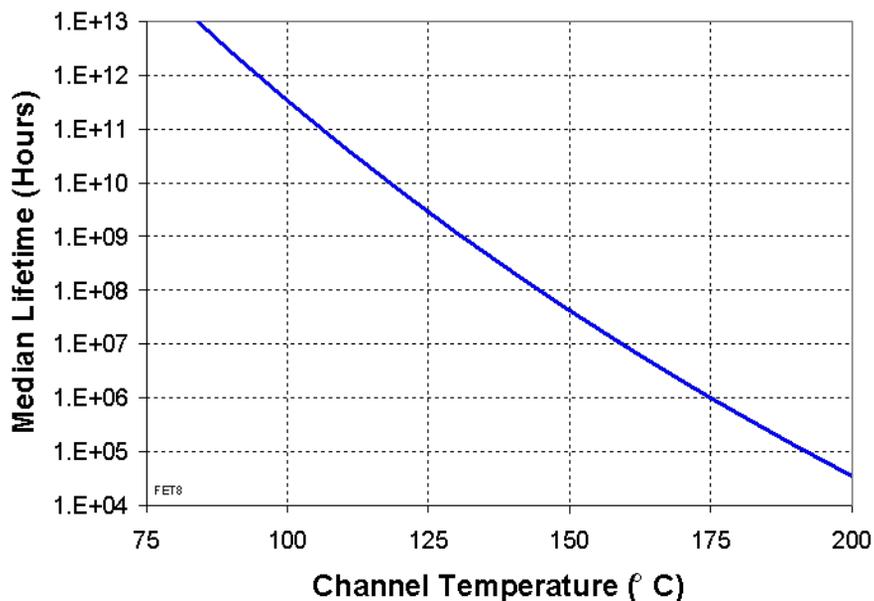
**Bias: Vd = 6 V, Id = 1.26 A, Vg = +0.6 V Typical**

<b>SYMBOL</b>	<b>PARAMETER</b>	<b>TEST CONDITIONS</b>	<b>MIN</b>	<b>NOMINAL</b>	<b>MAX</b>	<b>UNITS</b>
Gain	Small Signal Gain	F = 5.5 – 8.5 GHz	27	31		dB
IRL	Input Return Loss	F = 5.5 – 8.5 GHz		-12		dB
ORL	Output Return Loss	F = 5.5 – 8.5 GHz		-15		dB
Psat	Saturated Output Power	F = 5.5 – 8.5 GHz	32	34		dBm
P1dB	Output Power @ 1dB Compression	F = 5.5 – 8.5 GHz		32		dBm
TOI	Output TOI	F = 5.5 GHz	39	41		dBm
		F = 5.9 – 8.5 GHz	40	42		
NF	Noise Figure	F = 5.5 – 8.5 GHz		7		dB
	Gain Temperature Coefficient	F = 5.5 – 8.5 GHz		-0.03		dB/°C
	Power Temperature Coefficient	F = 5.5 – 8.5 GHz		-0.015		dBm/°C

**Table IV**  
**Power Dissipation and Thermal Properties**

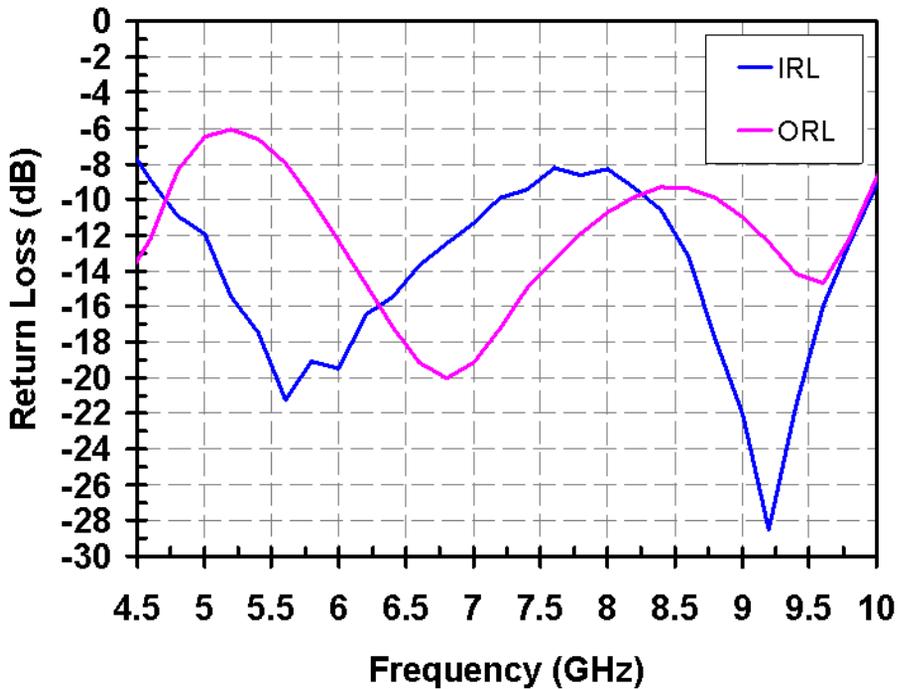
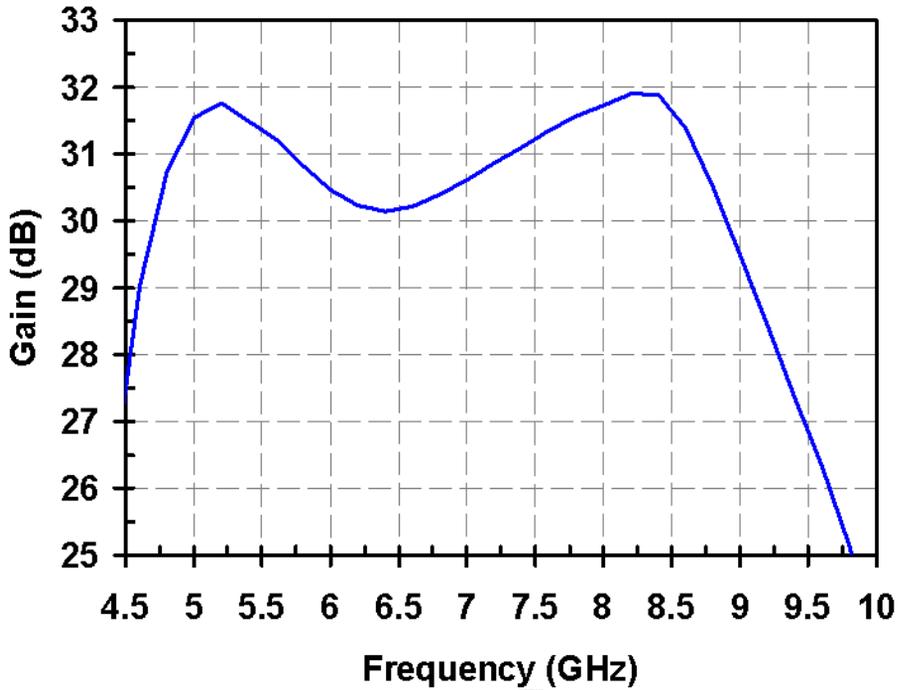
Parameter	Test Conditions	Value
Maximum Power Dissipation	Tbaseplate = 85 °C	Pd = 15 W Tchannel = 200 °C
Thermal Resistance, $\theta_{jc}$	Vd = 6 V Id = 1.26 A Pd = 7.56 W Tbaseplate = 85 °C	$\theta_{jc}$ = 7.7 °C/W Tchannel = 143 °C Tm = 1.3E+8 Hrs
Thermal Resistance, $\theta_{jc}$ Under RF Drive	Vd = 6 V Id = 1.7 A Pout = 34 dBm Pd = 7.7 W Tbaseplate = 85 °C	$\theta_{jc}$ = 7.7 °C/W Tchannel = 144 °C Tm = 1.1E+8 Hrs
Mounting Temperature	30 Seconds	320 °C
Storage Temperature		-65 to 150 °C

**Median Lifetime (Tm) vs. Channel Temperature**



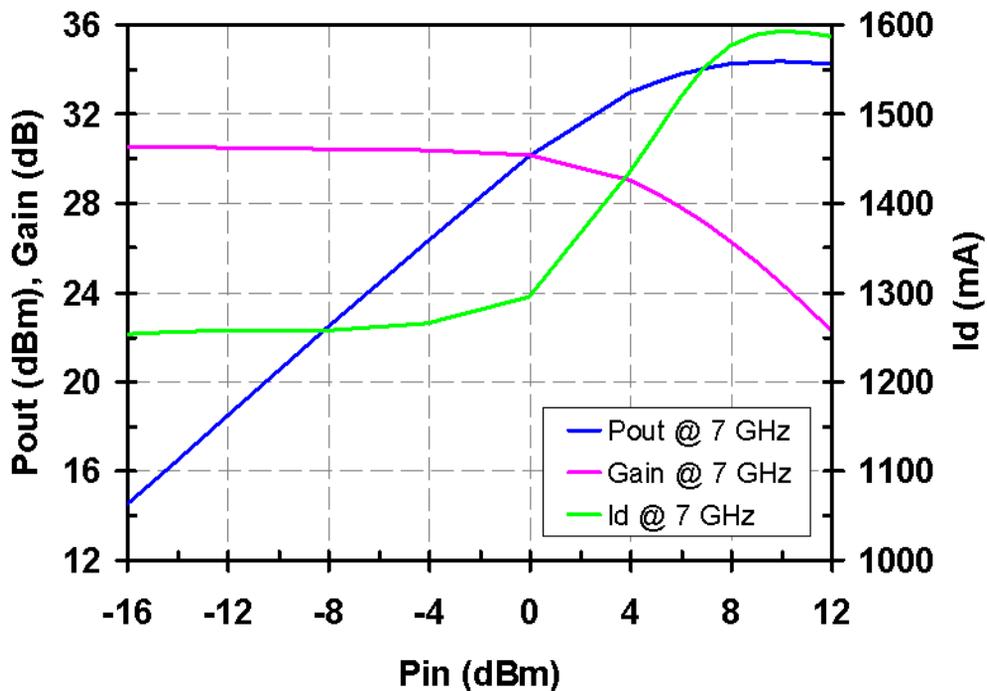
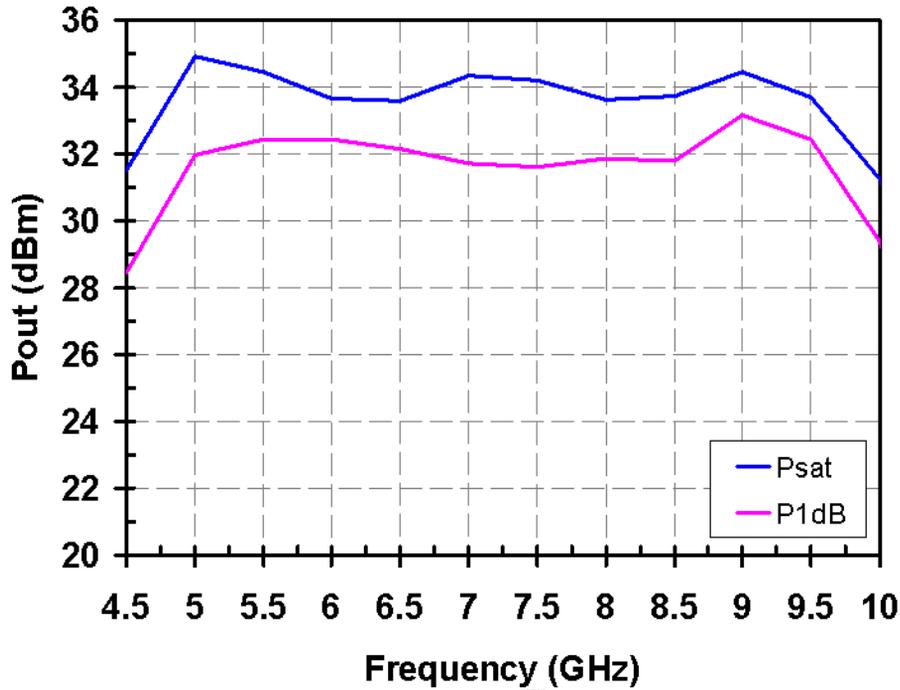
**Measured Data**

Bias conditions:  $V_d = 6\text{ V}$ ,  $I_d = 1.26\text{ A}$ ,  $V_g = +0.6\text{ V}$  Typical



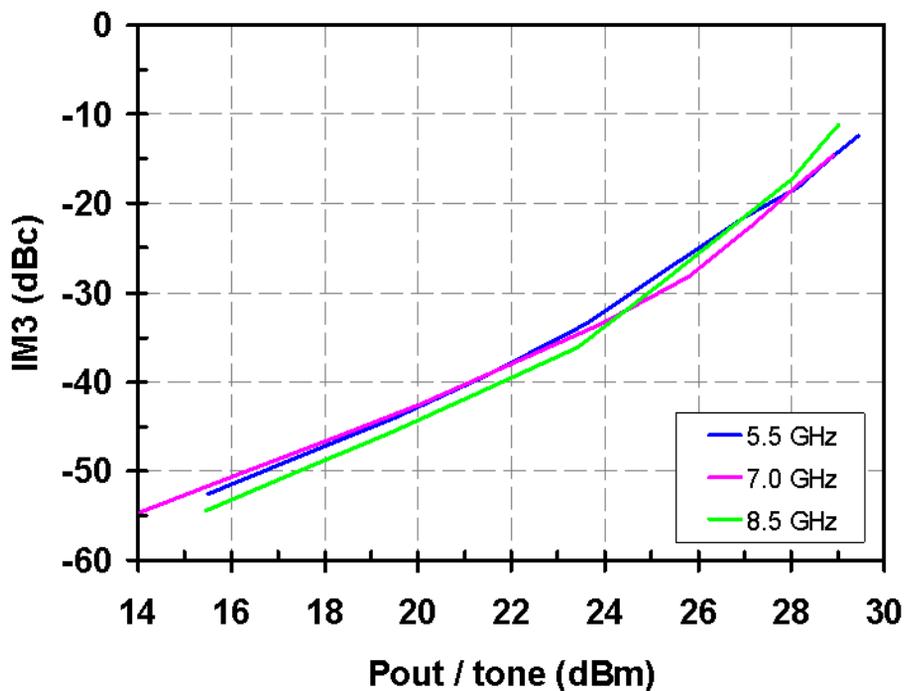
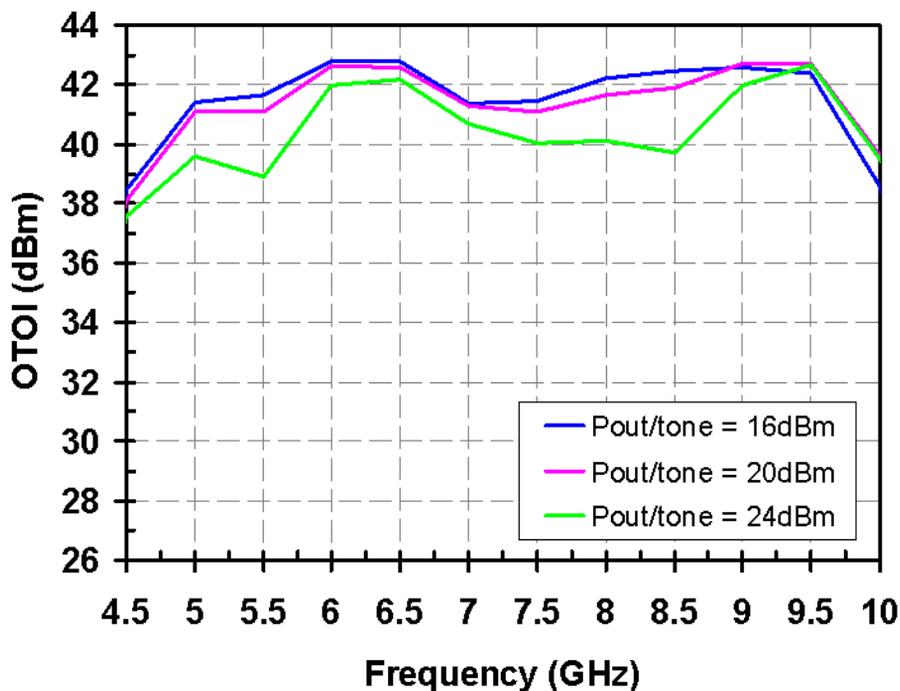
**Measured Data**

Bias conditions:  $V_d = 6\text{ V}$ ,  $I_d = 1.26\text{ A}$ ,  $V_g = +0.6\text{ V}$  Typical



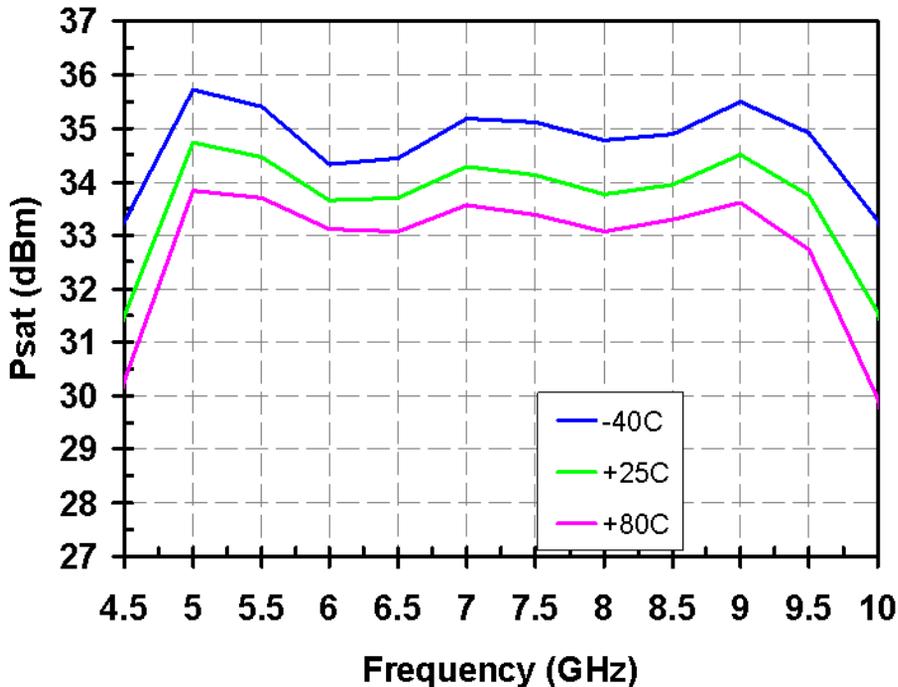
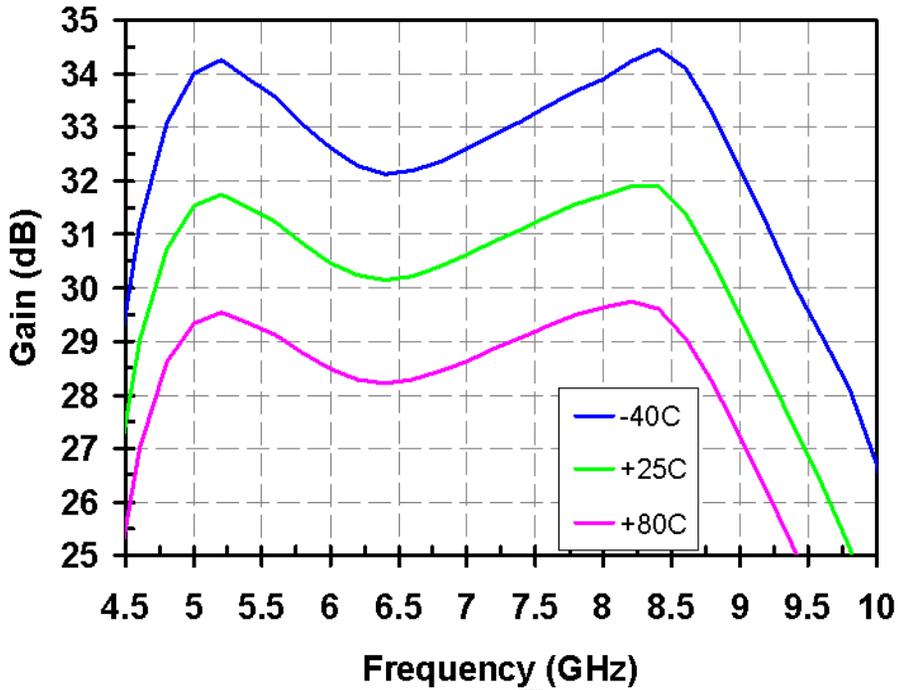
**Measured Data**

Bias conditions:  $V_d = 6\text{ V}$ ,  $I_d = 1.26\text{ A}$ ,  $V_g = +0.6\text{ V}$  Typical



**Measured Data**

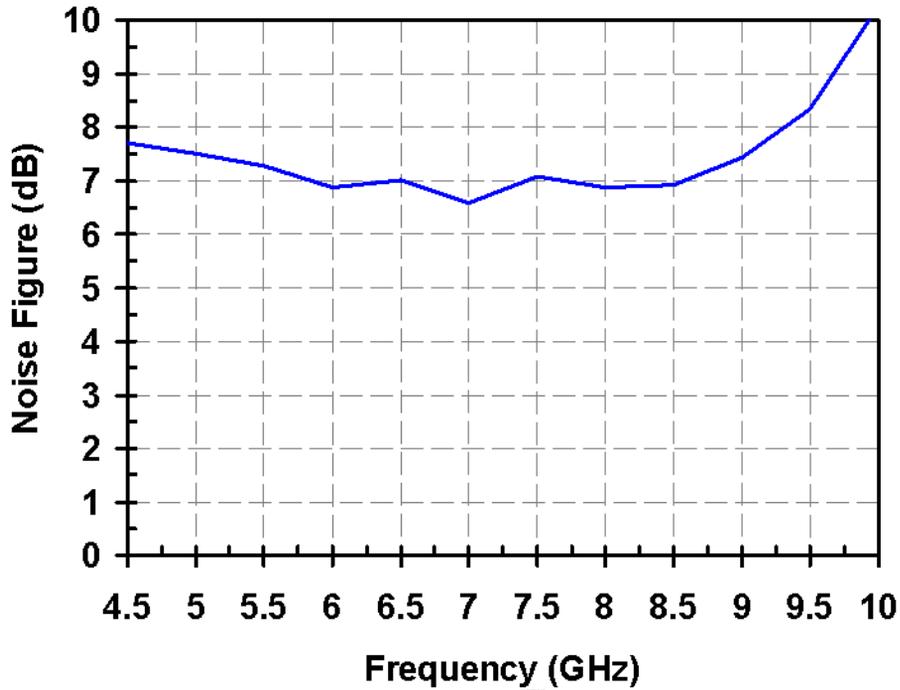
Bias conditions:  $V_d = 6\text{ V}$ ,  $I_d = 1.26\text{ A}$ ,  $V_g = +0.6\text{ V}$  Typical





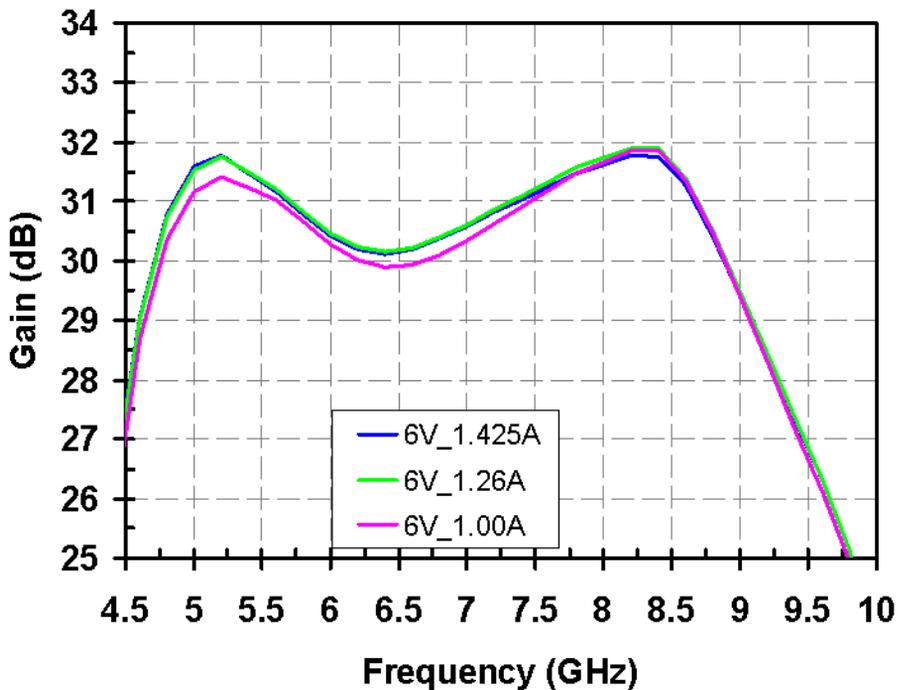
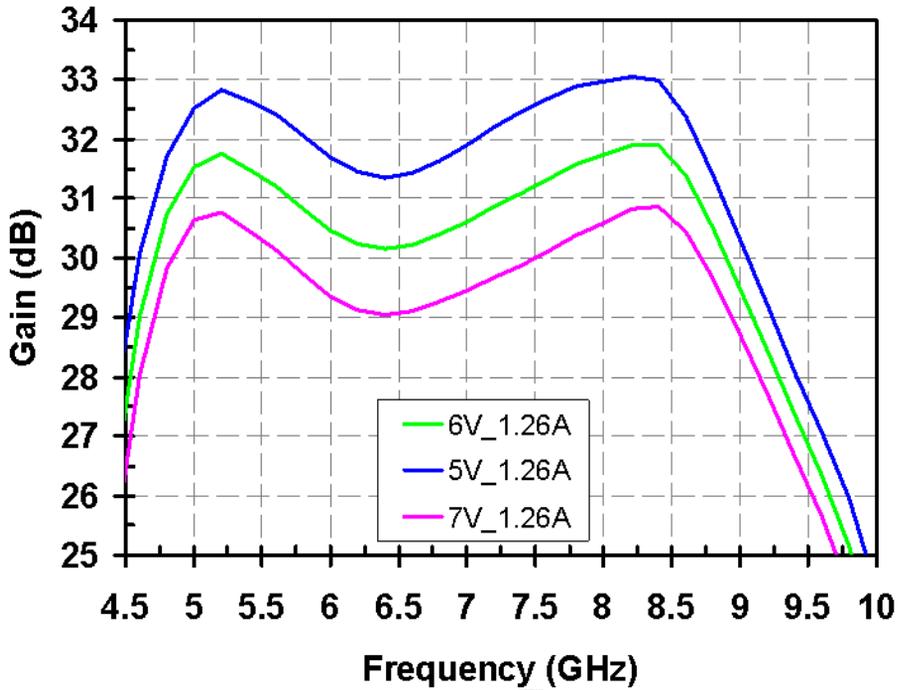
**Measured Data**

**Bias conditions:  $V_d = 6\text{ V}$ ,  $I_d = 1.26\text{ A}$ ,  $V_g = +0.6\text{ V}$  Typical**



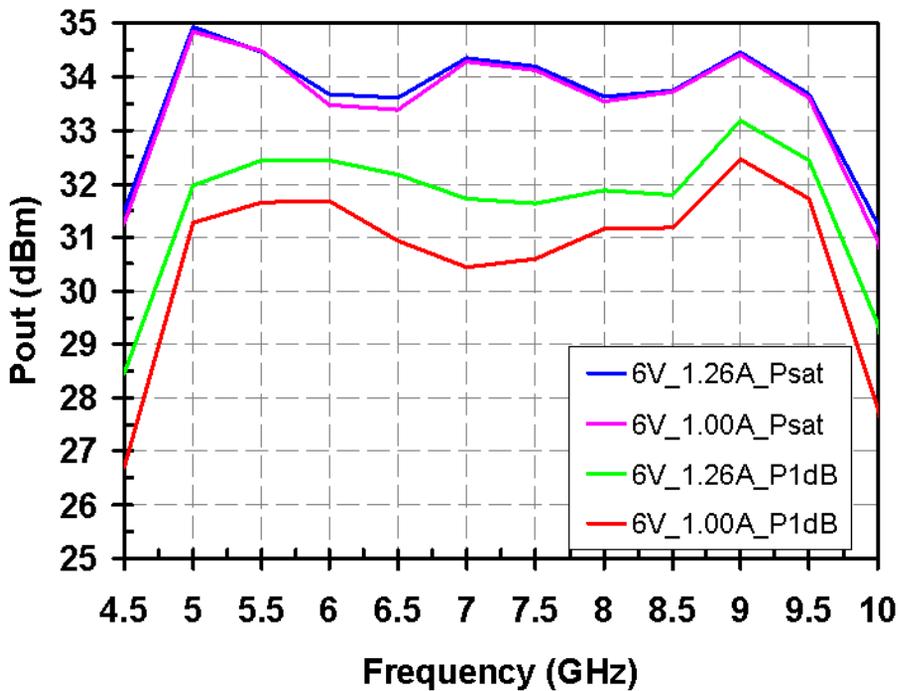
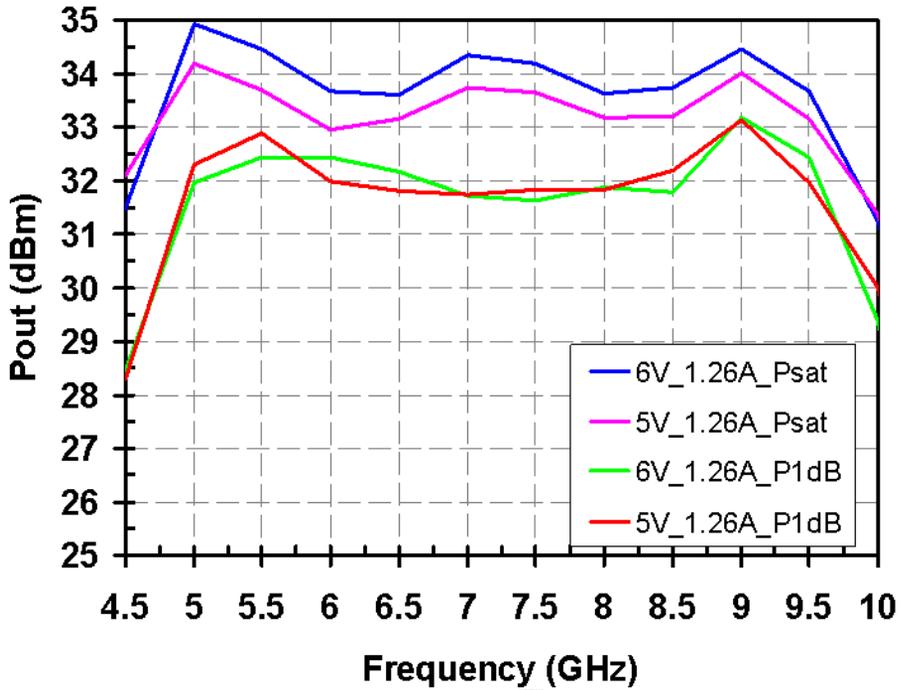
**Measured Data**

Bias conditions: Varies

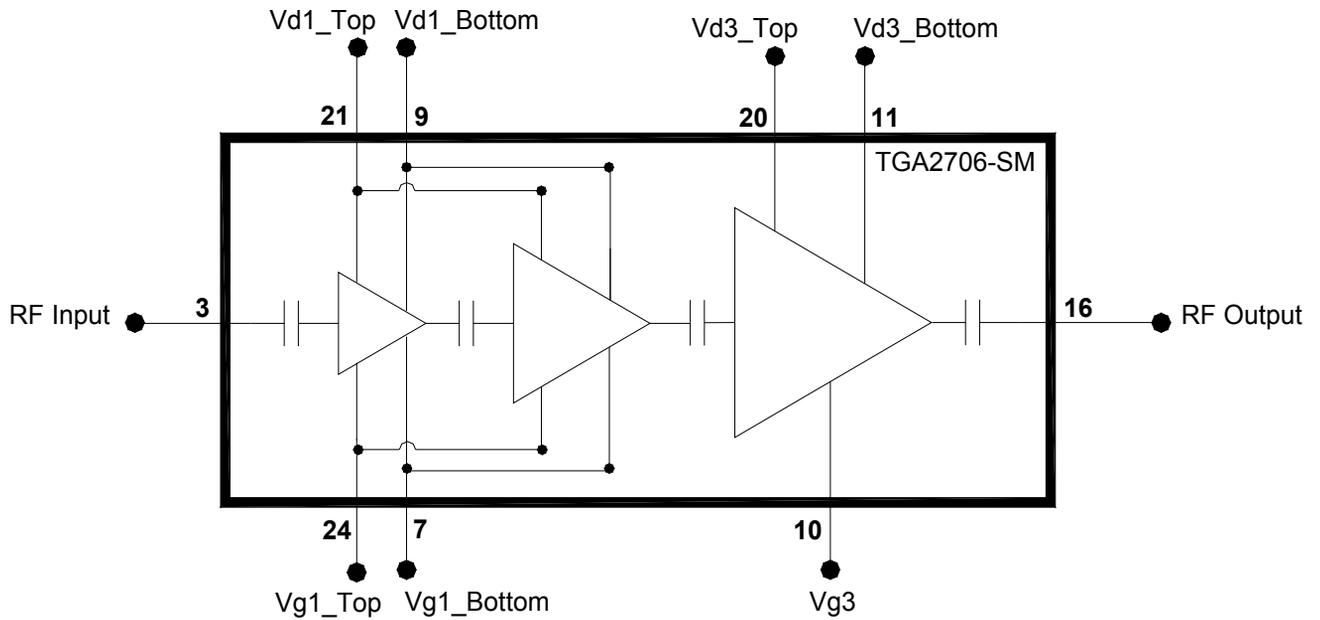


**Measured Data**

Bias conditions: Varies



**Electrical Schematic**



**Bias Procedures**

**Bias-up Procedure**

Vg set to 0 V

Vd\_set to +6 V

Adjust Vg more positive until Idq is 1.26 A.  
This will be ~ Vg = +0.6 V

**Bias-down Procedure**

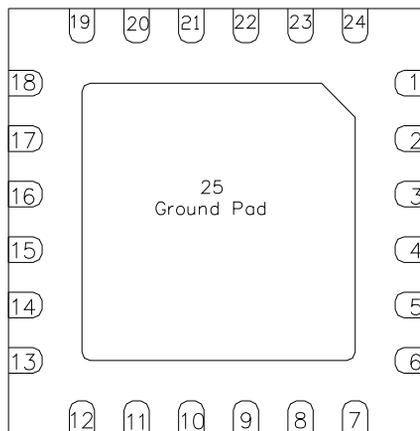
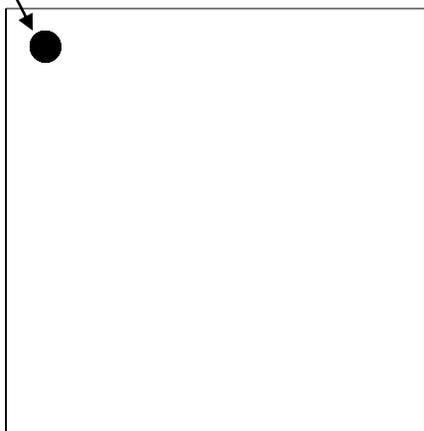
Turn off RF supply

Reduce Vg to 0 V. Ensure Id ~ 0 mA

Turn Vd to 0 V

## Package Pinout

Pin #1 Dot



Pin	Description
1, 2, 4, 5, 6, 13, 14, 15, 17, 18	N/C See Note 1
8, 12, 22, 23	N/C See Note 2
3	RF Input
7, 24	Vg1
9, 21	Vd1
10	Vg3
11, 20	Vd3
16	RF Output
19	See Note 1
25	Ground

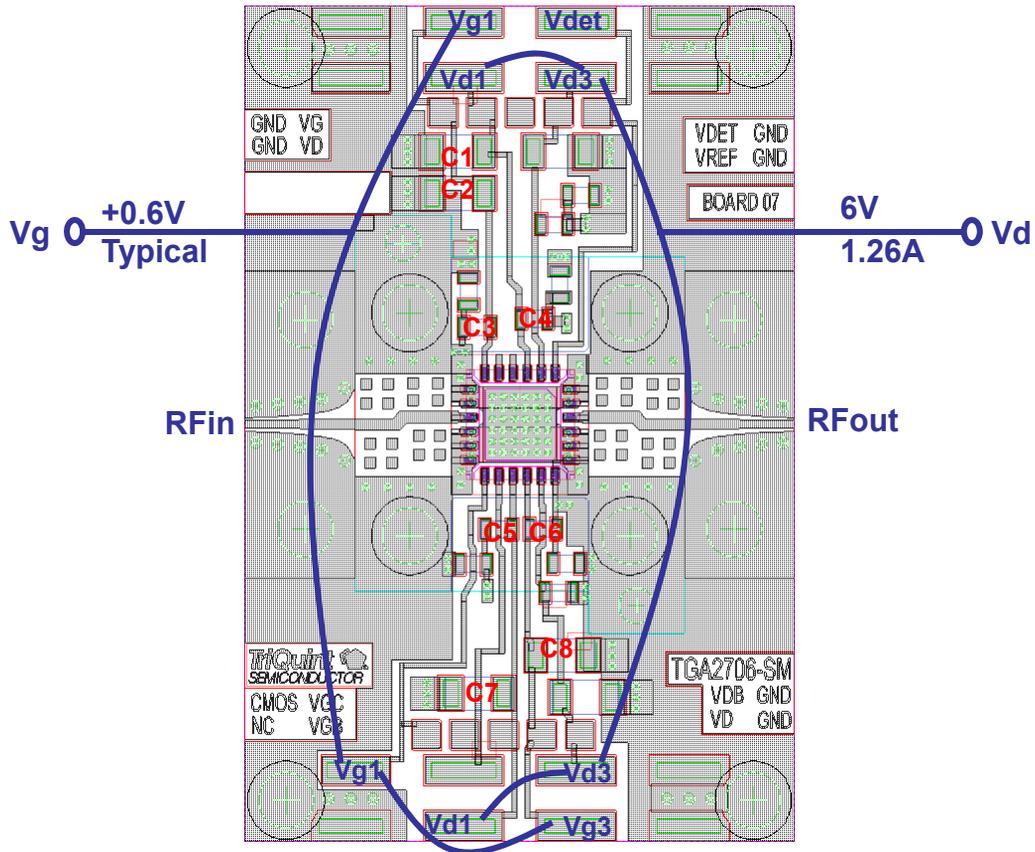
1/ No internal connection; must be grounded on PCB

2/ No internal connection; may be ground on PCB or left open

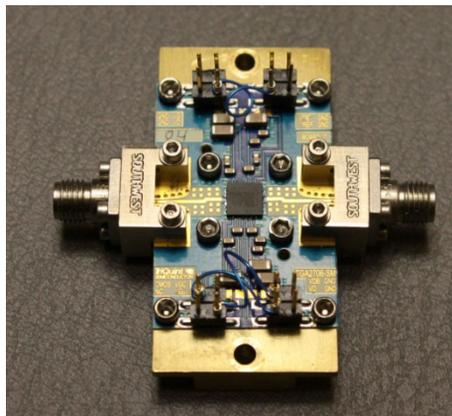
3/ Internally connected, but not for use in application.  
Recommended to leave open.



**Recommended Assembly Board**



Part	Description
C1, C2, C7, C8	1 uF Capacitor (1206)
C3, C4, C5, C6	0.01 uF Capacitor (0603)



Board is 10mil thick RO4350 with 0.5oz copper cladding.

Board is mounted on metal block and adequate heatsinking with fan is required.

**GaAs MMIC devices are susceptible to damage from Electrostatic Discharge. Proper precautions should be observed during handling, assembly and test.**

## Assembly Notes

### Recommended Surface Mount Package Assembly

- Proper ESD precautions must be followed while handling packages.
- Clean the board with acetone. Rinse with alcohol. Allow the circuit to fully dry.
- TriQuint recommends using a conductive solder paste for attachment. Follow solder paste and reflow oven vendors' recommendations when developing a solder reflow profile. Typical solder reflow profiles are listed in the table below.
- Hand soldering is not recommended. Solder paste can be applied using a stencil printer or dot placement. The volume of solder paste depends on PCB and component layout and should be well controlled to ensure consistent mechanical and electrical performance.
- Clean the assembly with alcohol.

## ESD and MSL Information

**ESD:** Class 0, Pass 200V.

**MSL:** Level 3.

## Typical Solder Reflow Profiles

Reflow Profile	SnPb	Pb Free
Ramp-up Rate	3 °C/sec	3 °C/sec
Activation Time and Temperature	60 – 120 sec @ 140 – 160 °C	60 – 180 sec @ 150 – 200 °C
Time above Melting Point	60 – 150 sec	60 – 150 sec
Max Peak Temperature	240 °C	260 °C
Time within 5 °C of Peak Temperature	10 – 20 sec	10 – 20 sec
Ramp-down Rate	4 – 6 °C/sec	4 – 6 °C/sec

## Ordering Information

Part	Package Style
TGA2706-SM	QFN 5x5 Surface Mount

***GaAs MMIC devices are susceptible to damage from Electrostatic Discharge. Proper precautions should be observed during handling, assembly and test.***